

QSZ4TR

QSZ4TR Information



Part Number	QSZ4TR
Manufacturer	Rohm Semiconductor
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Arrays
Description	TRANS NPN/PNP 30V 2A 5TSMT
Package	SOT-23-5 Thin, TSOT-23-5
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



QSZ4TR Specifications

	onductor Products polar (BJT) - Arrays TSOT-23-5
CategoryDiscrete Semical Transistors - BigPackageSOT-23-5 Thin, SoriesSeries-Transistor TypeNPN, PNP (Emiliant Current - Collector (Ic) (Max)Current - Collector (Ic) (Max)2AVoltage - Collector Emitter Breakdown (Max)30VVce Saturation (Max) @ Ib, Ic370mV @ 75mCurrent - Collector Cutoff (Max)100nA (ICBO)DC Current Gain (hFE) (Min) @ Ic, Vce270 @ 200mA,Power - Max1.25W	onductor Products polar (BJT) - Arrays TSOT-23-5
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DC Current Gain (hFE) (Min) @ Ic, Vce 270 @ 200mA, Power - Max 1.25W	A, 1.5A
Power - Max 1.25W	
	2V
Frequency - Transition 280MHz	
Operating Temperature 150°C (TJ)	
Mounting Type Surface Mount	
Package / Case SOT-23-5 Thin,	TSOT-23-5
Supplier Device Package TSMT5	

QSZ4TR Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

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Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about QSZ4TR, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com